NSN 5961-00-781-8989

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-781-8989
Inclosure Material:
Metal
Overall Length:
0.255 inches
Terminal Length:
1.500 inches
Overall Diameter:
0.365 inches
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open
Current Rating Per Characteristic:
1.00 amperes source cutoff current
Power Rating Per Characteristic:
800.0 milliwatts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0